

Rongping Wang

List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/4514970/publications.pdf>

Version: 2024-02-01

251
papers

5,004
citations

94433

37
h-index

128289

60
g-index

252
all docs

252
docs citations

252
times ranked

3442
citing authors

#	ARTICLE	IF	CITATIONS
1	Raman spectral study of silicon nanowires: High-order scattering and phonon confinement effects. <i>Physical Review B</i> , 2000, 61, 16827-16832.	3.2	255
2	Systematic z-scan measurements of the third order nonlinearity of chalcogenide glasses. <i>Optical Materials Express</i> , 2014, 4, 1011.	3.0	160
3	18-10 μ m mid-infrared supercontinuum generated in a step-index chalcogenide fiber using low peak pump power. <i>Optics Letters</i> , 2015, 40, 1081.	3.3	159
4	Mid-infrared supercontinuum generation in chalcogenides. <i>Optical Materials Express</i> , 2013, 3, 1075.	3.0	158
5	A broadband, quasi-continuous, mid-infrared supercontinuum generated in a chalcogenide glass waveguide. <i>Laser and Photonics Reviews</i> , 2014, 8, 792-798.	8.7	141
6	Mid-infrared supercontinuum covering 2.0 μ m to 16 μ m in a low-loss telluride single-mode fiber. <i>Laser and Photonics Reviews</i> , 2017, 11, 1700005.	8.7	136
7	Progress in optical waveguides fabricated from chalcogenide glasses. <i>Optics Express</i> , 2010, 18, 26635.	3.4	131
8	Properties of Ge _x As _y Se _{1-x-y} glasses for all-optical signal processing. <i>Optics Express</i> , 2008, 16, 2804.	3.4	124
9	Experimental demonstration of linearly polarized 2 μ m supercontinuum generation in a chalcogenide rib waveguide. <i>Optics Letters</i> , 2016, 41, 958.	3.3	96
10	Correlation between Structural and Physical Properties in Ge _{1-x} Sb _x Se Glasses. <i>Journal of Physical Chemistry C</i> , 2013, 117, 16571-16576.	3.1	89
11	High Brightness 2.2 μ m Mid-infrared Supercontinuum Generation in a Nontoxic Chalcogenide Step-index Fiber. <i>Journal of the American Ceramic Society</i> , 2016, 99, 2565-2568.	3.8	87
12	Unraveling the Crystallization Kinetics of Supercooled Liquid GeTe by Ultrafast Calorimetry. <i>Crystal Growth and Design</i> , 2017, 17, 3687-3693.	3.0	87
13	15 μ m midinfrared supercontinuum generation in a low-loss Te-based chalcogenide step-index fiber. <i>Optics Letters</i> , 2016, 41, 5222.	3.3	78
14	On the properties and stability of thermally evaporated Ge _{1-x} As _x Se thin films. <i>Applied Physics A: Materials Science and Processing</i> , 2009, 96, 615-625.	2.3	76
15	Supercontinuum generation in the mid-infrared from a dispersion-engineered As ₂ S ₃ glass rib waveguide. <i>Optics Letters</i> , 2012, 37, 3870.	3.3	75
16	Low Loss, High NA Chalcogenide Glass Fibers for Broadband Mid-infrared Supercontinuum Generation. <i>Journal of the American Ceramic Society</i> , 2015, 98, 1389-1392.	3.8	75
17	Ultrabroad supercontinuum generated from a highly nonlinear Ge _{1-x} Sb _x Se fiber. <i>Optics Letters</i> , 2016, 41, 3201.	3.3	73
18	Fundamental and Second-Order Raman Spectra of BaTiO ₃ . <i>Journal of Raman Spectroscopy</i> , 1996, 27, 31-34.	2.5	62

#	ARTICLE	IF	CITATIONS
19	Mid-infrared flattened supercontinuum generation in all-normal dispersion tellurium chalcogenide fiber. <i>Optics Express</i> , 2019, 27, 2036.	3.4	62
20	Phase change behaviors of Zn-doped Ge ₂ Sb ₂ Te ₅ films. <i>Applied Physics Letters</i> , 2012, 101, 051906.	3.3	61
21	Crystallization behaviors of Zn _x Sb _{100-x} thin films for ultralong data retention phase change memory applications. <i>CrystEngComm</i> , 2014, 16, 757-762.	2.6	60
22	Relative Contribution of Stoichiometry and Mean Coordination to the Fragility of Ge-As-Se Glass Forming Liquids. <i>Journal of Physical Chemistry B</i> , 2014, 118, 1436-1442.	2.6	57
23	The dependence of photosensitivity on composition for thin films of Ge _x As _y Se _{1-x-y} chalcogenide glasses. <i>Applied Physics A: Materials Science and Processing</i> , 2013, 113, 575-581.	2.3	52
24	Annealing induced phase transformations in amorphous As ₂ S ₃ films. <i>Journal of Applied Physics</i> , 2006, 100, 063524.	2.5	51
25	Mid-infrared optical nonlinearities of chalcogenide glasses in Ge-Sb-Se ternary system. <i>Optics Express</i> , 2015, 23, 1300.	3.4	48
26	Fabrication and characterization of multimaterial chalcogenide glass fiber tapers with high numerical apertures. <i>Optics Express</i> , 2015, 23, 23472.	3.4	48
27	Submicrometer-Thick Low-Loss As ₂ S ₃ Planar Waveguides for Nonlinear Optical Devices. <i>IEEE Photonics Technology Letters</i> , 2010, 22, 495-497.	2.5	44
28	Rebonding of Se to As and Ge in Ge ₃₃ As ₁₂ Se ₅₅ films upon thermal annealing: Evidence from x-ray photoelectron spectra investigations. <i>Journal of Applied Physics</i> , 2007, 101, 113517.	2.5	42
29	Observation of two elastic thresholds in Ge _x As _y Se _{1-x-y} glasses. <i>Journal of Applied Physics</i> , 2009, 105, .	2.5	40
30	Improved thermal and electrical properties of Al-doped Ge ₂ Sb ₂ Te ₅ films for phase-change random access memory. <i>Journal Physics D: Applied Physics</i> , 2012, 45, 375302.	2.8	40
31	Evaporated and solution deposited planar Sb ₂ S ₃ solar cells: A comparison and its significance. <i>Physica Status Solidi (A) Applications and Materials Science</i> , 2016, 213, 108-113.	1.8	40
32	Mid-infrared femtosecond laser-induced damages in As ₂ S ₃ and As ₂ Se ₃ chalcogenide glasses. <i>Scientific Reports</i> , 2017, 7, 6497.	3.3	40
33	Mid-infrared astrophotonics: study of ultrafast laser induced index change in compatible materials. <i>Optical Materials Express</i> , 2017, 7, 698.	3.0	40
34	Nb-doped CaTiO ₃ transparent semiconductor thin films. <i>Journal of Crystal Growth</i> , 2002, 245, 63-66.	1.5	39
35	Thermal annealing of arsenic tri-sulphide thin film and its influence on device performance. <i>Journal of Applied Physics</i> , 2010, 107, 053106.	2.5	39
36	Enhanced thermal stability and electrical behavior of Zn-doped Sb ₂ Te films for phase change memory application. <i>Applied Physics Letters</i> , 2013, 102, .	3.3	39

#	ARTICLE	IF	CITATIONS
37	Structural relaxation and optical properties in amorphous Ge ₃₃ As ₁₂ Se ₅₅ films. Journal of Non-Crystalline Solids, 2007, 353, 950-952.	3.1	37
38	Optical properties and structural correlations of GeAsSe chalcogenide glasses. Journal of Materials Science: Materials in Electronics, 2007, 18, 389-392.	2.2	37
39	Composition dependences of refractive index and thermo-optic coefficient in Ge-As-Se chalcogenide glasses. Journal of Non-Crystalline Solids, 2017, 459, 88-93.	3.1	37
40	Fabrication of low loss Ge ₃₃ As ₁₂ Se ₅₅ (AMTIR-1) planar waveguides. Applied Physics Letters, 2007, 91, 011115.	3.3	36
41	Optical and structural properties of Ge ₄₀ Sb ₄₀ Se ₂₀ thin films fabricated by sputtering and thermal evaporation. Journal of Alloys and Compounds, 2013, 548, 155-160.	5.5	36
42	Raman spectra of Ge _x As _y Se _{1-x-y} glasses. Journal of Applied Physics, 2009, 106, .	2.5	35
43	Second-harmonic generation in BaTiO ₃ films doped with cerium. Applied Physics Letters, 1998, 73, 2896-2898.	3.3	33
44	Plasma etching of As ₂ S ₃ films for optical waveguides. Journal of Non-Crystalline Solids, 2008, 354, 3179-3183.	3.1	31
45	Crystallization kinetics and thermal stability in Ge ₄₀ Sb ₄₀ Se ₂₀ glasses. Physica Status Solidi (B): Basic Research, 2013, 250, 59-64.	1.5	30
46	Effect of ZnO buffer layer on the quality of GaN films deposited by pulsed laser ablation. Thin Solid Films, 2002, 411, 69-75.	1.8	29
47	Thermal characterization of Ge ₄₀ As ₄₀ Se ₂₀ glasses by differential scanning calorimetry. Journal of Materials Science: Materials in Electronics, 2007, 18, 419-422.	2.2	29
48	Crystallization characteristics of Mg-doped Ge ₂ Sb ₂ Te ₅ films for phase change memory applications. Applied Surface Science, 2013, 264, 269-272.	6.1	29
49	High-resolution chalcogenide fiber bundles for infrared imaging. Optics Letters, 2015, 40, 4384.	3.3	29
50	Role of Ag in La _{1-x} Ag _x MnO ₃ manganite perovskite. Physical Review B, 2005, 71, .	3.2	28
51	Thin film deposition of Ge ₃₃ As ₁₂ Se ₅₅ by pulsed laser deposition and thermal evaporation: Comparison of properties. Journal of Non-Crystalline Solids, 2007, 353, 947-949.	3.1	28
52	Optical and structure properties of amorphous Ge ₄₀ Sb ₄₀ Se ₂₀ films for ultrafast all-optical signal processing. Journal of Alloys and Compounds, 2013, 580, 578-583.	5.5	28
53	A new direct process to prepare YBa ₂ Cu ₃ O _{7-δ} films on biaxially textured Ag{110}~211~%. Physica C: Superconductivity and Its Applications, 1999, 328, 37-43.	1.2	27
54	Fabrication and characteristics of CeO ₂ films on Si(100) substrates by pulsed laser deposition. Journal of Crystal Growth, 1999, 200, 505-509.	1.5	26

#	ARTICLE	IF	CITATIONS
55	Defects in silicon nanowires. Applied Physics Letters, 2006, 88, 142104.	3.3	26
56	Enhanced thermoelectric properties in Cu-doped Sb ₂ Te ₃ films. Vacuum, 2017, 145, 347-350.	3.5	25
57	Photo-induced and Thermal Annealing of Chalcogenide Films for Waveguide Fabrication. Physics Procedia, 2013, 48, 196-205.	1.2	24
58	Improved phase-change characteristics of Zn-doped amorphous Sb ₇ Te ₃ films for high-speed and low-power phase change memory. Applied Physics Letters, 2013, 103, .	3.3	24
59	Chemical environment of rare earth ions in Ge ₂₈ .125Ga _{6.25} Sb _{65.625} glass-ceramics doped with Dy ³⁺ . Applied Physics Letters, 2015, 107, 161901.	3.3	24
60	12â€“152â€“%â€“l¼m supercontinuum generation in a low-loss chalcogenide fiber pumped at a deep anomalous-dispersion region. Optics Letters, 2019, 44, 5545.	3.3	24
61	Dry etching characteristics of amorphous As ₂ S ₃ film in CHF ₃ plasma. Journal of Applied Physics, 2008, 104, .	2.5	23
62	A novel chalcogenide fiber with high nonlinearity and low material zeroâ€“dispersion via extrusion. Journal of the American Ceramic Society, 2019, 102, 5172-5179.	3.8	23
63	Nanoscale phase separation in ultrafast pulsed laser deposited arsenic trisulfide (As ₂ S ₃) films and its effect on plasma etching. Journal of Applied Physics, 2007, 102, .	2.5	22
64	Reversibility and Stability of ZnO-Sb ₂ Te ₃ Nanocomposite Films for Phase Change Memory Applications. ACS Applied Materials & Interfaces, 2014, 6, 8488-8496.	8.0	22
65	Near-zero anomalous dispersion Ge ₁₁₅ As ₂₄ Se ₆₄₅ glass nanowires for correlated photon pair generation: design and analysis. Optics Express, 2012, 20, 776.	3.4	21
66	Positive and negative phototunability of chalcogenide (AMTIR-1) microdisk resonator. Optics Express, 2015, 23, 8681.	3.4	21
67	Mid-infrared supercontinuum in well-structured As Se fibers based on peeled-extrusion. Optical Materials, 2019, 89, 402-407.	3.6	21
68	Conversion of pâ€“n conduction type by spinodal decomposition in Zn-Sb-Bi phase-change alloys. NPG Asia Materials, 2020, 12, .	7.9	21
69	Third-order nonlinear optical properties of Ge-As-Te chalcogenide glasses in mid-infrared. Optical Materials Express, 2020, 10, 1413.	3.0	21
70	Transition threshold in GexSb10Se90âˆ“x glasses. Journal of Applied Physics, 2014, 115, .	2.5	20
71	Structural investigation on GexSb10Se90âˆ“x glasses using x-ray photoelectron spectra. Journal of Applied Physics, 2014, 115, 183506.	2.5	20
72	Third-order optical nonlinear properties of amorphous Si/SiO ₂ superlattices fabricated by magnetron sputtering. Optics Communications, 2000, 176, 239-243.	2.1	19

#	ARTICLE	IF	CITATIONS
73	Impact of the ROHS directive on high-performance electronic systems. <i>Journal of Materials Science: Materials in Electronics</i> , 2006, 18, 331-346.	2.2	19
74	Structural evolution of Ge ₂ Sb ₂ Te ₅ films under the 488nm laser irradiation. <i>Materials Letters</i> , 2012, 88, 148-151.	2.6	19
75	Fabrication and characterization of bare Ge-Sb-Se chalcogenide glass fiber taper. <i>Infrared Physics and Technology</i> , 2017, 80, 105-111.	2.9	19
76	Role of cobalt in ZnO:Co thin films. <i>Journal Physics D: Applied Physics</i> , 2011, 44, 265002.	2.8	18
77	Structure and physical properties of Ge _x As _y Se _{1-x-y} glasses with the same mean coordination number of 2.5. <i>Journal of Applied Physics</i> , 2011, 109, .	2.5	18
78	Emission properties of erbium-doped Ge-Ga-Se glasses, thin films and waveguides for laser amplifiers. <i>Optical Materials Express</i> , 2014, 4, 464.	3.0	18
79	Thermal conductivity of Ge _x Sb _y Se _{100-x-y} glasses measured by Raman scattering spectra. <i>Journal of Raman Spectroscopy</i> , 2014, 45, 377-382.	2.5	18
80	Mid-infrared supercontinuum generation in a suspended-core tellurium-based chalcogenide fiber. <i>Optical Materials Express</i> , 2018, 8, 1341.	3.0	18
81	Intermediate crystallization kinetics in Germanium-Tellurides. <i>Acta Materialia</i> , 2019, 164, 473-480.	7.9	18
82	Advantages of Zn _{1.25} Sb ₂ Te ₃ material for phase change memory. <i>Materials Letters</i> , 2012, 87, 135-138.	2.6	17
83	Observation of photobleaching in Ge-deficient Ge _{16.8} Se _{83.2} chalcogenide thin film with prolonged irradiation. <i>Scientific Reports</i> , 2017, 7, 14585.	3.3	17
84	Fabrication and characterization of Ge ₂₀ Sb ₁₅ Se ₆₅ chalcogenide glass rib waveguides for telecommunication wavelengths. <i>Thin Solid Films</i> , 2013, 545, 462-465.	1.8	16
85	Silicon Mediated the Detoxification of Cr on Pakchoi (<i>Brassica Chinensis</i> L.) in Cr-contaminated Soil. <i>Procedia Environmental Sciences</i> , 2013, 18, 58-67.	1.4	16
86	Broadband mid-infrared supercontinuum generation in 1-meter-long As ₂ S ₃ -based fiber with ultra-large core diameter. <i>Optics Express</i> , 2016, 24, 28400.	3.4	16
87	Controllable Formation of the Crystalline Phases in Ge-Ga-S Chalcogenide Glass-Ceramics. <i>Journal of the American Ceramic Society</i> , 2017, 100, 74-80.	3.8	16
88	Nano-phase separation of arsenic tri-sulphide (As ₂ S ₃) film and its effect on plasma etching. <i>Journal of Non-Crystalline Solids</i> , 2007, 353, 953-955.	3.1	15
89	Pulsed laser deposited InGaZnO thin film on silica glass. <i>Journal of Non-Crystalline Solids</i> , 2012, 358, 2466-2469.	3.1	15
90	Elastic transition thresholds in Ge-As(Sb)-Se glasses. <i>Journal Physics D: Applied Physics</i> , 2013, 46, 165302.	2.8	15

#	ARTICLE	IF	CITATIONS
91	Chemical order in $GexAsySe_{1-x-y}$ glasses probed by high resolution X-ray photoelectron spectroscopy. Journal of Applied Physics, 2014, 115, .	2.5	15
92	Influence of the selenium content on thermo-mechanical and optical properties of $Ge\text{-}Ga\text{-}Sb\text{-}S$ chalcogenide glasses. Infrared Physics and Technology, 2016, 77, 21-26.	2.9	15
93	Broadband mid-infrared emission from Cr^{2+} in crystal-glass composite glasses by Hot Uniaxial Pressing. Journal of the American Ceramic Society, 2019, 102, 6618-6625.	3.8	15
94	A protective layer on As_2S_3 film for photo-resist patterning. Journal of Non-Crystalline Solids, 2008, 354, 5253-5254.	3.1	14
95	Photoluminescence in Er-doped Ge-As-Se chalcogenide thin films. Optical Materials Express, 2012, 2, 1270.	3.0	14
96	Greater than 50% inversion in Erbium doped Chalcogenide waveguides. Optics Express, 2016, 24, 23304.	3.4	14
97	Correlation among Structure, Water Peak Absorption, and Femtosecond Laser Ablation Properties of $Ge\text{-}Sb\text{-}Se$ Chalcogenide Glasses. Journal of Physical Chemistry C, 2018, 122, 1681-1687.	3.1	14
98	Growth of c-axis oriented GaN films on quartz by pulsed laser deposition. Optical Materials, 2003, 23, 15-20.	3.6	13
99	Tunable Ag surface-plasmon-resonance wavelength and its application on the photochromic behavior of $TiO_2\text{-}Ag$ films. Superlattices and Microstructures, 2009, 46, 159-165.	3.1	13
100	Structural investigations of $Ge_{50}As_{50}$ and $Ge_{15}As_{85}$ glasses using x-ray diffraction and extended x-ray fine structure spectroscopy. Journal of Physics Condensed Matter, 2012, 24, 385802.	1.8	13
101	Structural and physical properties of $Ge_{11.5}As_{24}S_{64.5-x}Se_{64.5}(1-x)$ glasses. Journal of Non-Crystalline Solids, 2015, 427, 16-19.	3.1	13
102	High content Er^{3+} -doped $25La_2O_3\text{-}75Ga_2O_3$ glass: A potential material for high-power lasers or EDWA. Journal of Alloys and Compounds, 2020, 837, 155477.	5.5	13
103	Effects of TiO_2 and ZrO_2 on optical properties of organic-inorganic hybrid polymers and thin films. Journal of Materials Science: Materials in Electronics, 2007, 18, 331-334.	2.2	12
104	Investigation of the structure of $GexAsySe_{1-x-y}$ glasses by x-ray photoelectron spectroscopy. Journal of Applied Physics, 2008, 103, 083537.	2.5	12
105	Mid-infrared supercontinuum covering 2.0-16 μ m in a low-loss telluride single-mode fiber (Laser) Tj ETQq1 1 0.784314 rgBT/Overlook	8.7	12
106	Resolving glass transition in Te-based phase-change materials by modulated differential scanning calorimetry. Applied Physics Express, 2017, 10, 105601.	2.4	12
107	1.8-2.7 μ m emission from As-S-Se chalcogenide glasses containing ZnSe: Cr^{2+} particles. Journal of Non-Crystalline Solids, 2019, 508, 21-25.	3.1	12
108	Low-Loss Chalcogenide Fiber Prepared by Double Peeled-Off Extrusion. Journal of Lightwave Technology, 2020, 38, 4533-4539.	4.6	12

#	ARTICLE	IF	CITATIONS
109	High-Q, submicron-confined chalcogenide microring resonators. Optics Express, 2021, 29, 33225.	3.4	12
110	Properties of YBa ₂ Cu ₃ O _x films on textured Ag tapes. Physica C: Superconductivity and Its Applications, 2000, 337, 101-105.	1.2	11
111	Ultraviolet lasing with low excitation intensity in deep-level emission free ZnO films. Journal of Crystal Growth, 2005, 282, 359-364.	1.5	11
112	Fluorine-doping concentration and fictive temperature dependence of self-trapped holes in SiO ₂ glasses. Journal of Applied Physics, 2005, 98, 023701.	2.5	11
113	SU-8 protective layer in photo-resist patterning on As ₂ S ₃ film. Physica Status Solidi C: Current Topics in Solid State Physics, 2011, 8, 3183-3186.	0.8	11
114	Amorphous (In ₂ O ₃) _x (Ga ₂ O ₃) _y (ZnO) _{1-x-y} thin films with high mobility fabricated by pulsed laser deposition. Applied Surface Science, 2013, 282, 700-703.	6.1	11
115	Evidence of homopolar bonds in chemically stoichiometric Ge _x As _y Se _{1-x-y} glasses. Applied Physics Express, 2015, 8, 015504.	1.4	11
116	Creation of ZnS nanoparticles by laser ablation in water. Applied Physics A: Materials Science and Processing, 2016, 122, 1.	2.3	11
117	High quality, high index-contrast chalcogenide microdisk resonators. Optics Express, 2021, 29, 17775.	3.4	11
118	Photo-induced effects in Ge-As-Se films in various states. Optical Materials Express, 2020, 10, 540.	3.0	11
119	Photo-bleaching of self-trapped holes in SiO ₂ glass. Journal of Non-Crystalline Solids, 2005, 351, 1569-1572.	3.1	10
120	The effect of defects on the optical nonlinearity of thermally poled SiO _x thin films. Thin Solid Films, 2008, 516, 5474-5477.	1.8	10
121	Improvement of thermal stability and phase change behavior of Ge ₂ Sb ₂ Te ₅ thin films by Calcium doping. Journal of Non-Crystalline Solids, 2020, 549, 120338.	3.1	10
122	Arsenic-free low-loss sulfide glass fiber for mid-infrared supercontinuum generation. Infrared Physics and Technology, 2021, 113, 103618.	2.9	10
123	Ultrafast laser micromachining the ultra-low expansion glass-ceramic: Optimization of processing parameters and physical mechanism. Journal of the European Ceramic Society, 2021, 41, 5990-5999.	5.7	10
124	Physical Aging of Arsenic Trisulfide Thick Films and Bulk Materials. Journal of the American Ceramic Society, 2007, 90, 1269-1271.	3.8	9
125	Bonding trends within ternary isocoordinate chalcogenide glasses Ge _x As _y Se _{1-x-y} . Physical Chemistry Chemical Physics, 2013, 15, 4582.	2.8	9
126	Structure and properties of Ge-Sb-S-CsCl glass-ceramics. Materials Chemistry and Physics, 2014, 147, 545-549.	4.0	9

#	ARTICLE	IF	CITATIONS
127	New Methods Versus Old Questions: Crystallization Kinetics of S, Se, and Te. <i>Crystal Growth and Design</i> , 2019, 19, 1103-1110.	3.0	9
128	Sb-rich ZnSbTe phase-change materials: A candidate for the trade-off between crystallization speed and data retention. <i>Applied Physics Express</i> , 2014, 7, 105801.	2.4	8
129	Structural Modeling of Ge _{6.25} As _{32.5} Se _{61.25} Using a Combination of Reverse Monte Carlo and Ab Initio Molecular Dynamics. <i>Journal of Physical Chemistry A</i> , 2014, 118, 4790-4796.	2.5	8
130	The effect of thermal annealing on (In ₂ O ₃) _{0.75} (Ga ₂ O ₃) _{0.1} (ZnO) _{0.15} thin films with high mobility. <i>Vacuum</i> , 2014, 107, 191-194.	3.5	8
131	Fabrication and characterization of chalcogenide polarization-maintaining fibers based on extrusion. <i>Optical Fiber Technology</i> , 2017, 39, 26-31.	2.7	8
132	Experimental investigation on the high-order modes in supercontinuum generation from step-index As ₂ S fibers. <i>Applied Physics B: Lasers and Optics</i> , 2018, 124, 1.	2.2	8
133	High-power all-fiber wavelength-widely-tunable Tm ³⁺ -doped fiber laser Q-switched by TI-SA. <i>Journal of Optics (United Kingdom)</i> , 2019, 21, 085501.	2.2	8
134	Understanding the complicated crystallization behaviors in Germanium-Tellurides. <i>Journal of Non-Crystalline Solids</i> , 2020, 531, 119862.	3.1	8
135	Investigation of tellurium-based chalcogenide double-clad fiber for coherent mid-infrared supercontinuum generation. <i>Optical Fiber Technology</i> , 2020, 55, 102144.	2.7	8
136	Optical properties and thermal stability of amorphous GeSbSe films. <i>Journal of Non-Crystalline Solids</i> , 2020, 532, 119888.	3.1	8
137	Extruded seven-core tellurium chalcogenide fiber for mid-infrared. <i>Optical Materials Express</i> , 2019, 9, 3863.	3.0	8
138	PROPERTIES AND STRUCTURE OF Ag-DOPED As ₂ Se ₃ GLASSES. <i>Journal of Nonlinear Optical Physics and Materials</i> , 2007, 16, 49-57.	1.8	7
139	Surface Roughness in Plasma-Etched As ₂ S ₃ Films: Its Origin and Improvement. <i>IEEE Nanotechnology Magazine</i> , 2008, 7, 285-290.	2.0	7
140	Unique interface-driven crystallization mechanism and element-resolved structure imaging of ZnO-Ge ₂ Sb ₂ Te ₅ nanocomposites. <i>Ceramics International</i> , 2018, 44, 22497-22503.	4.8	7
141	Crystallization kinetics with fragile-to-strong crossover in Zn-Sb-Te supercooled phase-change liquids. <i>Applied Physics Letters</i> , 2019, 115, .	3.3	7
142	Ultra-high germanium-contained Se-chalcogenide glass fiber for mid-infrared. <i>Infrared Physics and Technology</i> , 2020, 104, 103112.	2.9	7
143	Iodine-doped Ge-As-Se glasses with high purity and low dispersion. <i>Spectrochimica Acta - Part A: Molecular and Biomolecular Spectroscopy</i> , 2020, 229, 117885.	3.9	7
144	Dissipative soliton resonance in a simple linear cavity Tm ³⁺ -doped double clad fiber laser with dispersion management. <i>Journal of Optics (United Kingdom)</i> , 2020, 22, 035505.	2.2	7

#	ARTICLE	IF	CITATIONS
145	Large mode-area chalcogenide multicore fiber prepared by continuous two-stage extrusion. <i>Optical Materials Express</i> , 2021, 11, 791.	3.0	7
146	Mid-infrared supercontinuum generation in low-loss single-mode Te-rich chalcogenide fiber. <i>Optical Materials Express</i> , 2019, 9, 3487.	3.0	7
147	Crystallization kinetics of monatomic antimony. <i>Applied Physics Letters</i> , 2021, 119, .	3.3	7
148	Mid-Infrared Single-Mode Ge-As-S Fiber for High Power Laser Delivery. <i>Journal of Lightwave Technology</i> , 2022, 40, 2151-2156.	4.6	7
149	Optical properties of amorphous Si/SiO ₂ superlattice. <i>Superlattices and Microstructures</i> , 2000, 28, 157-163.	3.1	6
150	Stress reduction by ion bombardment in CeO ₂ films. <i>Solid State Communications</i> , 2000, 114, 613-616.	1.9	6
151	Deposition of high-temperature superconducting films on biaxially textured Ni(001) substrates. <i>Physica C: Superconductivity and Its Applications</i> , 2000, 337, 87-90.	1.2	6
152	Self-oxidized NiO on cube-textured Ni for YBCO coated superconductor. <i>Physica C: Superconductivity and Its Applications</i> , 2000, 339, 166-170.	1.2	6
153	In situ hole doping of wide-gap semiconductors by dual-target simultaneous laser ablation: GaN and SiC epitaxial films. <i>Applied Physics Letters</i> , 2005, 87, 162106.	3.3	6
154	Fast crystallization and low-power amorphization of Mg ²⁺ Sb ²⁺ Te reversible phase-change films. <i>CrystEngComm</i> , 2014, 16, 7401-7405.	2.6	6
155	Emission properties of Er ³⁺ -doped Ge ₂₀ Ga ₅ Sb ₁₀ Se ₆₅ glasses in near- and mid-infrared. <i>Infrared Physics and Technology</i> , 2018, 89, 277-281.	2.9	6
156	Structure and physical properties of Ge ₁₅ Sb ₂₀ Se ₆₅ x S _x glasses. <i>Journal of the American Ceramic Society</i> , 2018, 101, 201-207.	3.8	6
157	X-ray photoelectron spectra of Ge-As-Te glasses. <i>AIP Advances</i> , 2018, 8, 075208.	1.3	6
158	Improved phase-change properties of Sn ²⁺ Zn ²⁺ Sb alloys with a two-step crystallization process for multi-level data storage applications. <i>Ceramics International</i> , 2019, 45, 16442-16449.	4.8	6
159	Ultra-large mode area mid-infrared fiber based on chalcogenide glasses extrusion. <i>Journal of the American Ceramic Society</i> , 2021, 104, 343-349.	3.8	6
160	Effects of Ca doping on the crystallization kinetics of GeTe. <i>Applied Physics Letters</i> , 2021, 118, .	3.3	6
161	Fragile-to-strong crossover in optimized In-Sb-Te phase-change supercooled liquids. <i>Physical Review Materials</i> , 2020, 4, .	2.4	6
162	Integrated shadow mask for sampled Bragg gratings in chalcogenide (As ₂ S ₃) planar waveguides. <i>Optics Express</i> , 2007, 15, 7708.	3.4	5

#	ARTICLE	IF	CITATIONS
163	Identifying the best chalcogenide glass compositions for the application in mid-infrared waveguides. Proceedings of SPIE, 2015, , .	0.8	5
164	Ab Initio Comparison of Bonding Environments and Threshold Behavior in Ge _x As ₁₀ Se _{90-x} and Ge _x Sb ₁₀ Se _{90-x} Glass Models. Journal of Physical Chemistry A, 2015, 119, 6421-6427.	2.5	5
165	Optical and structural properties of Ge-Ga-Te amorphous thin films fabricated by magnetron sputtering. Infrared Physics and Technology, 2017, 86, 181-186.	2.9	5
166	Shortening Nucleation Time to Enable Ultrafast Phase Transition in Zn ₁ Sb ₇ Te ₁₂ Pseudo-Binary Alloy. Langmuir, 2018, 34, 15143-15149.	3.5	5
167	Dispersion tuning and supercontinuum generating in novel W-typed chalcogenide fiber. Infrared Physics and Technology, 2020, 111, 103538.	2.9	5
168	Can two-dimensional confinement trigger the fragile-to-strong crossover in phase-change supercooled liquids. Scripta Materialia, 2021, 192, 89-93.	5.2	5
169	Third-order optical nonlinearity in Ge-Se-Te chalcogenide glasses. Optical Materials, 2021, 117, 111208.	3.6	5
170	Design and fabrication of As ₂ Se ₃ chalcogenide waveguides with low optical losses. Applied Optics, 2020, 59, 1564.	1.8	5
171	Distributions of self-trapped hole continuums in silica glass. Journal of Applied Physics, 2006, 100, 013706.	2.5	4
172	Te-based chalcogenide films with high thermal stability for phase change memory. Journal of Applied Physics, 2012, 111, 093514.	2.5	4
173	The feasibility of Sn, In, or Al doped ZnSb thin film as candidates for phase change material. Journal of Applied Physics, 2016, 120, 015301.	2.5	4
174	Understanding the fast crystallization kinetics of In ₂ Sb ₂ Te by using ultrafast calorimetry. CrystEngComm, 2018, 20, 159-163.	2.6	4
175	Fabrication and Characterization of Three-hole As ₂ S ₃ Suspended-Core Fibers Based on Robust Extrusion. IEEE Access, 2018, 6, 41093-41098.	4.2	4
176	Femto- and nano-second laser-induced damages in chalcogenide glasses. Japanese Journal of Applied Physics, 2019, 58, 080911.	1.5	4
177	Study of glass transition kinetics of As ₂ S ₃ and As ₂ Se ₃ by ultrafast differential scanning calorimetry. Chinese Physics B, 2019, 28, 047802.	1.4	4
178	Enhancement of luminescence in Er ³⁺ doped Ge ₂₀ Ga ₁₀ S ₇₀ glass-ceramics. Optical Materials, 2020, 100, 109677.	3.6	4
179	Mid-infrared single-Mode As-S-Se glass fiber and its supercontinuum generation. Journal of Non-Crystalline Solids, 2021, 567, 120925.	3.1	4
180	Self-mode-locking and self-phase modulation in Tm ³⁺ -doped double clad fiber laser for pulse peak power enhancement and multi-wavelength generation. Optics and Laser Technology, 2021, 141, 107128.	4.6	4

#	ARTICLE	IF	CITATIONS
181	Dispersion-tunable chalcogenide tri-cladding fiber based on novel continuous two-stage extrusion. <i>Optical Materials Express</i> , 2020, 10, 1034.	3.0	4
182	Single-mode suspended large-core chalcohalide fiber with a low zero-dispersion wavelength for supercontinuum generation. <i>Optics Express</i> , 2022, 30, 641.	3.4	4
183	Ultrashort Gaussian pulse-width expansion and shape deformation induced by group velocity dispersion. <i>JETP Letters</i> , 2006, 84, 425-429.	1.4	3
184	Investigation of bonding within ab initio models of GeAsSe glasses. <i>Chemical Physics Letters</i> , 2013, 575, 97-100.	2.6	3
185	Spraying Silicon and/or Cerium Sols Favorably Mediated Enhancement of Cd/Pb Tolerance in Lettuce Grown in Combined Cd/Pb Contaminated Soil. <i>Procedia Environmental Sciences</i> , 2013, 18, 68-77.	1.4	3
186	Epitaxial growth of Sc ₂ O ₃ films on Gd ₂ O ₃ -buffered Si substrates by pulsed laser deposition. <i>Applied Physics A: Materials Science and Processing</i> , 2016, 122, 1.	2.3	3
187	Concentration-dependent and enhanced luminescence in Ge _{23.5} Ga _{11.5} Se ₆₅ glasses and glass-ceramics doped with Er ³⁺ . <i>Optical Materials</i> , 2017, 67, 1-6.	3.6	3
188	The ability of Ge _x Ga _{4-x} S _{96-x} chalcogenide glasses dissolving rare earth probed by x-ray photoelectron spectra analysis. <i>Materials Research Express</i> , 2019, 6, 085212.	1.6	3
189	Generation of 100ÂnJ pulse, 1ÂW average power at from an intermode beating mode-locked all-fiber laser. <i>High Power Laser Science and Engineering</i> , 2019, 7, .	4.6	3
190	High Q Chalcogenide Photonic Crystal Nanobeam Cavities. <i>IEEE Photonics Technology Letters</i> , 2021, 33, 525-528.	2.5	3
191	Influence of extrusion on the properties of chalcogenide glasses and fibers. <i>Optics Communications</i> , 2022, 513, 128091.	2.1	3
192	Se-H-free As ₂ Se ₃ fiber and its spectral applications in the mid-infrared. <i>Optics Express</i> , 2022, 30, 24072.	3.4	3
193	STRUCTURAL AND OPTICAL CHARACTERIZATION OF ZnO SINGLE CRYSTALLINE NANOBAMBOOS. <i>International Journal of Modern Physics B</i> , 2005, 19, 2804-2810.	2.0	2
194	Surface Oxidation of Ge ₃₃ As ₁₂ Se ₅₅ Films. <i>Journal of the American Ceramic Society</i> , 2008, 91, 2371-2373.	3.8	2
195	Quantitative estimation of crystallization kinetics in GeGaS and Au-doped GeGaS glass-ceramics. <i>Journal of the American Ceramic Society</i> , 2020, 103, 1593-1599.	3.8	2
196	The transport mechanisms at localized states of thin films of GexAsySe1-x-y chalcogenide glasses under off-equilibrium conditions. <i>Thin Solid Films</i> , 2020, 709, 138044.	1.8	2
197	Multiple singularities of optical properties in GexTe100-x films. <i>Infrared Physics and Technology</i> , 2020, 106, 103280.	2.9	2
198	Micro-Structure Changes Caused by Thermal Evolution in Chalcogenide GexAsySe1-x-y Thin Films by In Situ Measurements. <i>Materials</i> , 2021, 14, 2572.	2.9	2

#	ARTICLE	IF	CITATIONS
199	Low loss and dispersion engineered ZnSe waveguides at telecom wavelengths. AIP Advances, 2021, 11, 065303.	1.3	2
200	Suppression of photo-induced effects in chemically stoichiometric Ge ₂₆ 67Ga ₈ S ₆ 533 glasses. Optical Materials Express, 2021, 11, 2413.	3.0	2
201	Short-pulse gain-switched Raman fiber laser based on conventional silica fibers. Optics and Laser Technology, 2021, 141, 107154.	4.6	2
202	Structural characteristics of <i>c</i> -axis-oriented PrBa ₂ Cu ₃ O ₇ thin films grown by pulsed laser deposition. Journal of Crystal Growth, 1999, 204, 293-297.	1.5	1
203	Preparation of Ni-based multilayered tape and its potential application for the coating of YBa ₂ Cu ₃ O _{7-δ} . Physica C: Superconductivity and Its Applications, 2000, 337, 96-100.	1.2	1
204	High quality YBCO superconductive thin films fabricated by laser molecular beam epitaxy. Science in China Series A: Mathematics, 2001, 44, 947-952.	0.5	1
205	Optical characterization of Ge-As-Se glasses containing high content of germanium. , 2006, , .		1
206	Advanced processing methods for As ₂ S ₃ Waveguide Fabrication. , 2006, , .		1
207	Fabrication and Optical Characterization of Ge ₃₃ As ₁₂ Se ₅₅ (AMTIR-1) Thin Film Waveguides. , 2006, , .		1
208	Mid infrared supercontinuum generation from chalcogenide glass waveguides and fibers. , 2015, , .		1
209	Can the copper completely suppress the photodarkening effect in As-Se films. Infrared Physics and Technology, 2020, 104, 103159.	2.9	1
210	Intermode beating mode-locking: Toward compact 2 μ m short-pulse all-fiber lasers. Optical Fiber Technology, 2020, 58, 102253.	2.7	1
211	A W-Type Double-Cladding IR Fiber With Ultra-High Numerical Aperture. Journal of Lightwave Technology, 2021, 39, 2158-2163.	4.6	1
212	Direct generation of 7 W, 360 μ m multi-pulse laser from an ultra-compact all-fiber gain switched Tm ³⁺ -doped double-clad fiber laser. IEEE Photonics Technology Letters, 2021, , 1-1.	2.5	1
213	Affect of ZnO Thin Film of Pulsed Laser Deposition by Substrate Temperatures. Zhongguo Jiguang/Chinese Journal of Lasers, 2009, 36, 1539-1544.	1.2	1
214	Supercontinuum generation in the mid-infrared using dispersion engineered chalcogenide glass waveguides. , 2013, , .		1
215	Spectroscopy Application of Linearly Polarized 2-10 μ m Supercontinuum in a Chalcogenide Rib Waveguide. , 2016, , .		1
216	Dependence of thermal stability in the composition of Ge-As-Te films. Optical Materials Express, 2020, 10, 2944.	3.0	1

#	ARTICLE	IF	CITATIONS
217	CeO ₂ thin films grown on biaxially textured nickel (001). Science Bulletin, 1998, 43, 1718-1722.	1.7	0
218	Novel Shadow Mask Structure for Sampled Bragg Gratings in Chalcogenide (As ₂ S ₃) Planar Waveguides. , 2007, , .		0
219	Optimization of the Structural and Optical Properties of Ge-As-Se Glasses. , 2007, , .		0
220	High Quality Comb Filters in Chalcogenide Rib Waveguides. , 2007, , .		0
221	Characteristics of Ge-As-Se chalcogenide glasses and films. , 2007, , .		0
222	Highly Optical Nonlinear Ag-doped As ₂ Se ₃ Glasses: Preparation and Characterization. , 2007, , .		0
223	Fabrication Process Development for As ₂ S ₃ Planar Waveguides using Standard Semiconductor Processing. , 2007, , .		0
224	Investigation of intensity and spectrum of silicon nanowires by ESR. , 2007, , .		0
225	Fabrication of As ₂ S ₃ Planar Waveguides with Very Low Propagation Loss. Conference Proceedings - Lasers and Electro-Optics Society Annual Meeting-LEOS, 2007, , .	0.0	0
226	Fabrication of GaN/ZnO bilayers on sapphire by pulsed laser ablation-deposition. Physica Status Solidi C: Current Topics in Solid State Physics, 2007, 4, 1427-1431.	0.8	0
227	The evolution of bond structure in Ge ₃₃ As ₁₂ Se ₅₅ films upon thermal annealing. Journal of Non-Crystalline Solids, 2008, 354, 5264-5265.	3.1	0
228	Nonlinear materials for integrated ultra-fast all-optical devices. , 2008, , .		0
229	Fabrication of sub-micron Thick, low loss As ₂ S ₃ planar waveguides. , 2009, , .		0
230	Properties and stability of Ge-As-Se evaporated thin films for nonlinear waveguides. , 2009, , .		0
231	Optically nonlinear chalcogenide glasses for all- optical signal processing. , 2009, , .		0
232	Energy levels of self-trapped holes in amorphous SiO ₂ : fictive temperature dependence. Journal Physics D: Applied Physics, 2009, 42, 095418.	2.8	0
233	Chalcogenide glasses for nonlinear photonics. , 2010, , .		0
234	Green light-induced annealing of As ₂ S ₃ thin films and its impact on waveguides performance. , 2010, , .		0

#	ARTICLE	IF	CITATIONS
235	Photoluminescence in Er-doped Ge-As-Se chalcogenide thin films. , 2011, , .		0
236	The impact of thermal- and photo-annealing of chalcogenide films for optical waveguides. , 2011, , .		0
237	Silver-doped arsenic selenide ($\text{Ag-As}_{2/3}\text{-Se}_{3/3}$) waveguides for compact nonlinear optical devices. , 2012, , .		0
238	A two-octave broadband quasi-continuous mid-infrared supercontinuum generated in a chalcogenide glass waveguide. , 2014, , .		0
239	A Broadband Mid-Infrared Supercontinuum Generated in a Short Chalcogenide Glass Waveguide. , 2014, , .		0
240	On-line temperature measurement using single-ended distributed cascading fiber Bragg gratings-based Brillouin optical fiber sensor. Measurement Science and Technology, 2019, 30, 035105.	2.6	0
241	Optic fiber temperature sensor based on cascading fiber Bragg gratings. AIP Advances, 2019, 9, 015206.	1.3	0
242	Research on determining of cations in GeAsSe chalcogenide glass. Journal of Non-Crystalline Solids, 2021, 553, 120466.	3.1	0
243	High extinction ratio microstructure fiber based on chalcogenide glasses. Journal of the American Ceramic Society, 2021, 104, 5671-5678.	3.8	0
244	$\text{Ge}_{11.5}\text{As}_{24}\text{Se}_{64.5}$ Glass: a New Material for the Fabrication of Highly Nonlinear ($\sim 33,000\text{W}^{-1}\text{km}^{-1}$) Dispersion Engineered Waveguides. , 2009, , .		0
245	Chalcogenide glass waveguides for the mid-infrared. , 2013, , .		0
246	Waveguides for Nonlinear Optics in the Mid-Infrared. , 2017, , .		0
247	Photonic mid-infrared nulling for exoplanet detection on a planar chalcogenide platform. , 2018, , .		0
248	Fabrication of high-Q $\text{Ge}_{28}\text{Sb}_{12}\text{Se}_{60}$ chalcogenide microring resonators in telecommunication band. , 2020, , .		0
249	All-fiber wavelength-widely tunable multi-pulse gain-switched Tm^{3+} -doped double-clad fiber laser. Optics and Laser Technology, 2022, 148, 107710.	4.6	0
250	Research on a novel chalcogenide glass and its physical optics properties. Infrared Physics and Technology, 2022, 122, 104079.	2.9	0
251	Low-loss single-mode Ge-As-Se glass fiber and its supercontinuum generation for mid-infrared. Optics Communications, 2022, 515, 128189.	2.1	0